

MUN5233DW1, NSBC143ZDXV6, NSBC143ZDP6

Dual NPN Bias Resistor Transistors R1 = 4.7 kΩ, R2 = 47 kΩ

NPN Transistors with Monolithic Bias Resistor Network

This series of digital transistors is designed to replace a single device and its external resistor bias network. The Bias Resistor Transistor (BRT) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space.

Features

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

(T_A = 25°C, common for Q₁ and Q₂, unless otherwise noted)

| Rating | Symbol | Max | Unit |
|--------------------------------|----------------------|-----|------|
| Collector-Base Voltage | V _{CBO} | 50 | Vdc |
| Collector-Emitter Voltage | V _{CEO} | 50 | Vdc |
| Collector Current – Continuous | I _C | 100 | mAdc |
| Input Forward Voltage | V _{IN(fwd)} | 30 | Vdc |
| Input Reverse Voltage | V _{IN(rev)} | 5 | Vdc |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

ORDERING INFORMATION

| Device | Package | Shipping† |
|----------------------------------|---------|-------------------|
| MUN5233DW1T1G, SMUN5233DW1T1G | SOT-363 | 3,000/Tape & Reel |
| NSBC143ZDXV6T1G | SOT-563 | 4,000/Tape & Reel |
| NSBC143ZDXV6T5G | SOT-563 | 8,000/Tape & Reel |
| NSBC143ZDP6T5G | SOT-963 | 8,000/Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



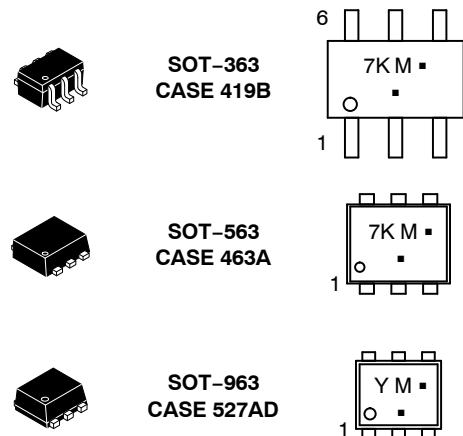
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PIN CONNECTIONS



MARKING DIAGRAMS



7K/Y = Specific Device Code
M = Date Code*
■ = Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation may vary depending upon manufacturing location.

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THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|----------------|--------|-----|------|
|----------------|--------|-----|------|

MUN5233DW1 (SOT-363) ONE JUNCTION HEATED

| | | | | |
|--|----------------------|-----------------|------------|---------------------------|
| Total Device Dissipation $T_A = 25^\circ\text{C}$ | (Note 1) (Note 2) | P_D | 187 256 | mW |
| Derate above 25°C | (Note 1) (Note 2) | | 1.5 2.0 | mW/ $^\circ\text{C}$ |
| Thermal Resistance, Junction to Ambient | (Note 1) (Note 2) | $R_{\theta JA}$ | 670 490 | $^\circ\text{C}/\text{W}$ |

MUN5233DW1 (SOT-363) BOTH JUNCTION HEATED (Note 3)

| | | | | |
|--|----------------------|-----------------|-------------|---------------------------|
| Total Device Dissipation $T_A = 25^\circ\text{C}$ | (Note 1) (Note 2) | P_D | 250 385 | mW |
| Derate above 25°C | (Note 1) (Note 2) | | 2.0 3.0 | mW/ $^\circ\text{C}$ |
| Thermal Resistance, Junction to Ambient | (Note 1) (Note 2) | $R_{\theta JA}$ | 493 325 | $^\circ\text{C}/\text{W}$ |
| Thermal Resistance, Junction to Lead | (Note 1) (Note 2) | $R_{\theta JL}$ | 188 208 | $^\circ\text{C}/\text{W}$ |
| Junction and Storage Temperature Range | | T_J, T_{stg} | -55 to +150 | $^\circ\text{C}$ |

NSBC143ZDXV6 (SOT-563) ONE JUNCTION HEATED

| | | | | |
|--|----------|-----------------|-----|---------------------------|
| Total Device Dissipation $T_A = 25^\circ\text{C}$ | (Note 1) | P_D | 357 | mW |
| Derate above 25°C | (Note 1) | | 2.9 | mW/ $^\circ\text{C}$ |
| Thermal Resistance, Junction to Ambient | (Note 1) | $R_{\theta JA}$ | 350 | $^\circ\text{C}/\text{W}$ |

NSBC143ZDXV6 (SOT-563) BOTH JUNCTION HEATED (Note 3)

| | | | | |
|--|----------|-----------------|-------------|---------------------------|
| Total Device Dissipation $T_A = 25^\circ\text{C}$ | (Note 1) | P_D | 500 | mW |
| Derate above 25°C | (Note 1) | | 4.0 | mW/ $^\circ\text{C}$ |
| Thermal Resistance, Junction to Ambient | (Note 1) | $R_{\theta JA}$ | 250 | $^\circ\text{C}/\text{W}$ |
| Junction and Storage Temperature Range | | T_J, T_{stg} | -55 to +150 | $^\circ\text{C}$ |

NSBC143ZDP6 (SOT-963) ONE JUNCTION HEATED

| | | | | |
|--|----------------------|-----------------|------------|---------------------------|
| Total Device Dissipation $T_A = 25^\circ\text{C}$ | (Note 4) (Note 5) | P_D | 231 269 | MW |
| Derate above 25°C | (Note 4) (Note 5) | | 1.9 2.2 | mW/ $^\circ\text{C}$ |
| Thermal Resistance, Junction to Ambient | (Note 4) (Note 5) | $R_{\theta JA}$ | 540 464 | $^\circ\text{C}/\text{W}$ |

NSBC143ZDP6 (SOT-963) BOTH JUNCTION HEATED (Note 3)

| | | | | |
|--|----------------------|-----------------|-------------|---------------------------|
| Total Device Dissipation $T_A = 25^\circ\text{C}$ | (Note 4) (Note 5) | P_D | 339 408 | MW |
| Derate above 25°C | (Note 4) (Note 5) | | 2.7 3.3 | mW/ $^\circ\text{C}$ |
| Thermal Resistance, Junction to Ambient | (Note 4) (Note 5) | $R_{\theta JA}$ | 369 306 | $^\circ\text{C}/\text{W}$ |
| Junction and Storage Temperature Range | | T_J, T_{stg} | -55 to +150 | $^\circ\text{C}$ |

- FR-4 @ Minimum Pad.
- FR-4 @ 1.0×1.0 Inch Pad.
- Both junction heated values assume total power is sum of two equally powered channels.
- FR-4 @ 100 mm^2 , 1 oz. copper traces, still air.
- FR-4 @ 500 mm^2 , 1 oz. copper traces, still air.

MUN5233DW1, NSBC143ZDXV6, NSBC143ZDP6

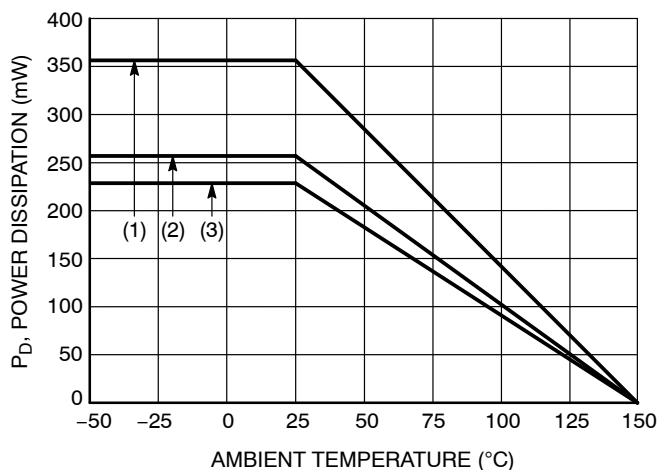
ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, common for Q_1 and Q_2 , unless otherwise noted)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|---|---------------|-----|-----|------|------|
| OFF CHARACTERISTICS | | | | | |
| Collector-Base Cutoff Current ($V_{CB} = 50\text{ V}$, $I_E = 0$) | I_{CBO} | - | - | 100 | nAdc |
| Collector-Emitter Cutoff Current ($V_{CE} = 50\text{ V}$, $I_B = 0$) | I_{CEO} | - | - | 500 | nAdc |
| Emitter-Base Cutoff Current ($V_{EB} = 6.0\text{ V}$, $I_C = 0$) | I_{EBO} | - | - | 0.18 | mAdc |
| Collector-Base Breakdown Voltage ($I_C = 10\ \mu\text{A}$, $I_E = 0$) | $V_{(BR)CBO}$ | 50 | - | - | Vdc |
| Collector-Emitter Breakdown Voltage (Note 6) ($I_C = 2.0\text{ mA}$, $I_B = 0$) | $V_{(BR)CEO}$ | 50 | - | - | Vdc |

ON CHARACTERISTICS

| | | | | | |
|---|---------------|------|-----|-------|------------|
| DC Current Gain (Note 6) ($I_C = 5.0\text{ mA}$, $V_{CE} = 10\text{ V}$) | h_{FE} | 80 | 200 | - | |
| Collector-Emitter Saturation Voltage (Note 6) ($I_C = 10\text{ mA}$, $I_B = 1.0\text{ mA}$) | $V_{CE(sat)}$ | - | - | 0.25 | V |
| Input Voltage (Off) ($V_{CE} = 5.0\text{ V}$, $I_C = 100\ \mu\text{A}$) | $V_{i(off)}$ | - | 0.6 | - | Vdc |
| Input Voltage (On) ($V_{CE} = 0.2\text{ V}$, $I_C = 5.0\text{ mA}$) | $V_{i(on)}$ | - | 0.9 | - | Vdc |
| Output Voltage (On) ($V_{CC} = 5.0\text{ V}$, $V_B = 2.5\text{ V}$, $R_L = 1.0\text{ k}\Omega$) | V_{OL} | - | - | 0.2 | Vdc |
| Output Voltage (Off) ($V_{CC} = 5.0\text{ V}$, $V_B = 0.5\text{ V}$, $R_L = 1.0\text{ k}\Omega$) | V_{OH} | 4.9 | - | - | Vdc |
| Input Resistor | R1 | 3.3 | 4.7 | 6.1 | k Ω |
| Resistor Ratio | R_1/R_2 | 0.55 | 0.1 | 0.185 | |

6. Pulsed Condition: Pulse Width = 300 ms, Duty Cycle \leq 2%.



- (1) SOT-363; 1.0 x 1.0 Inch Pad
- (2) SOT-563; Minimum Pad
- (3) SOT-963; 100 mm², 1 oz. Copper Trace

Figure 1. Derating Curve

MUN5233DW1, NSBC143ZDXV6, NSBC143ZDP6

TYPICAL CHARACTERISTICS
MUN5233DW1, NSBC143ZDXV6

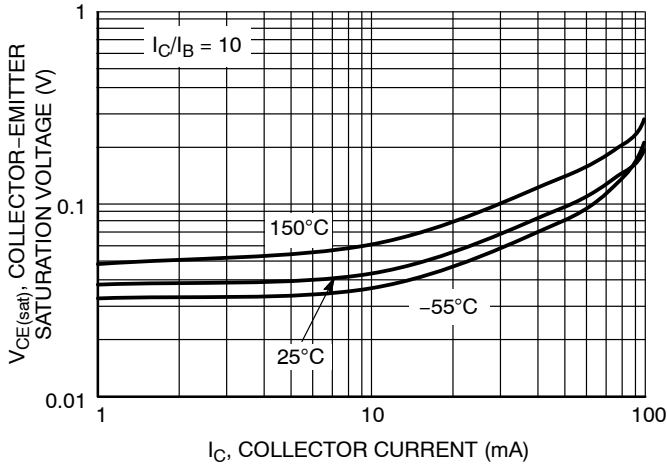


Figure 2. $V_{CE(sat)}$ vs. I_C

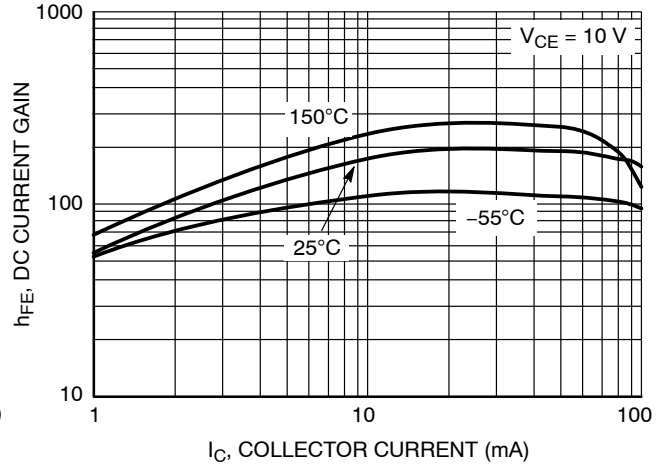


Figure 3. DC Current Gain

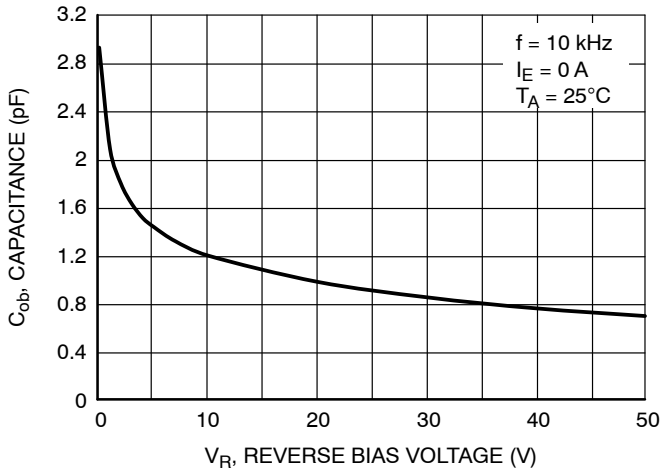


Figure 4. Output Capacitance

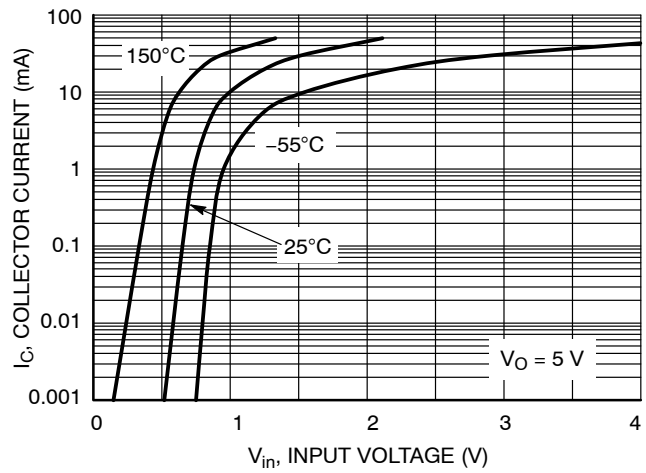


Figure 5. Output Current vs. Input Voltage

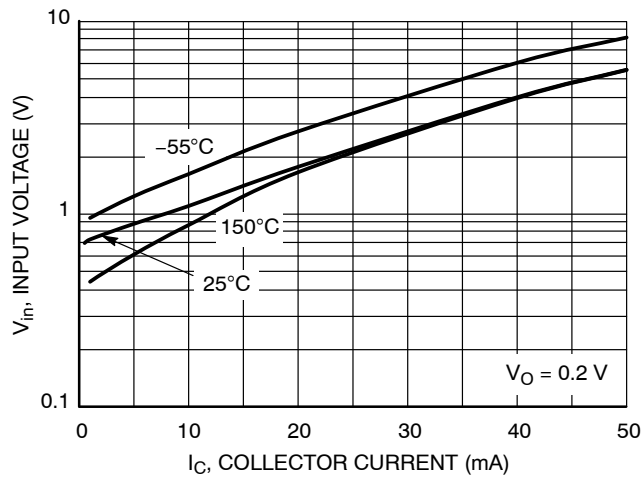


Figure 6. Input Voltage vs. Output Current

TYPICAL CHARACTERISTICS
NSBC143ZDP6

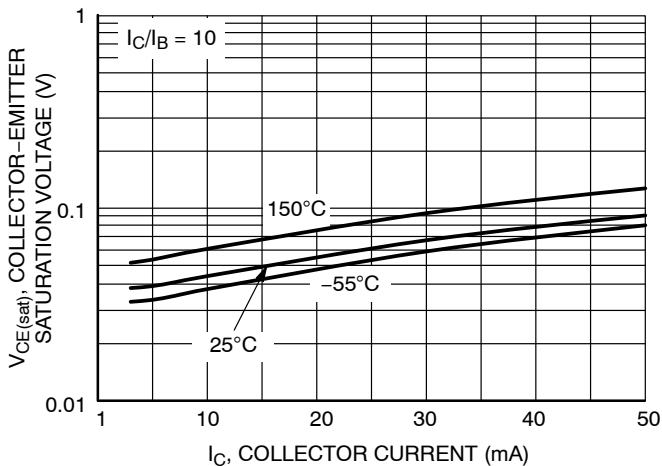


Figure 7. $V_{CE(sat)}$ vs. I_C

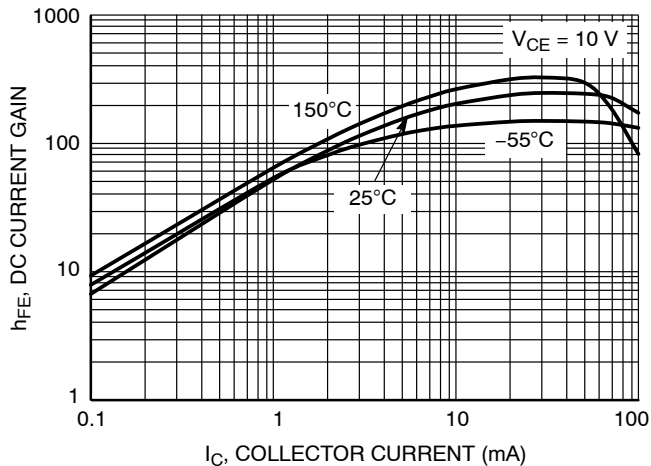


Figure 8. DC Current Gain

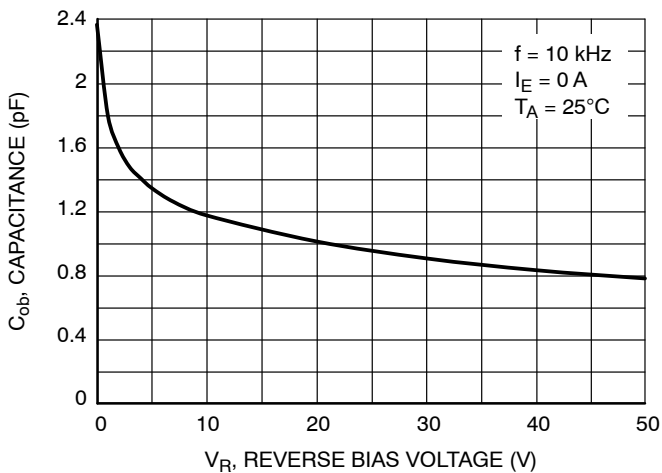


Figure 9. Output Capacitance

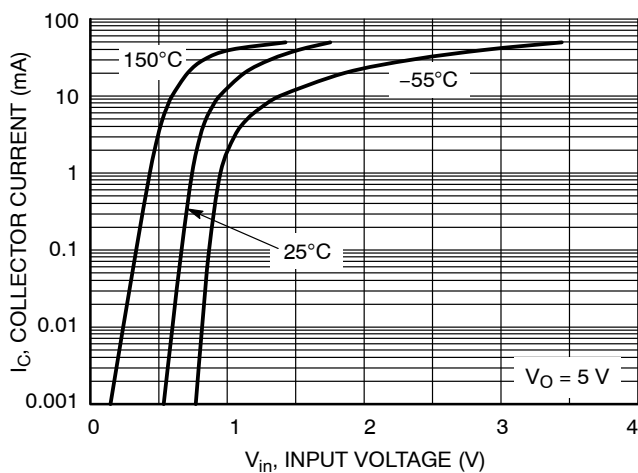


Figure 10. Output Current vs. Input Voltage

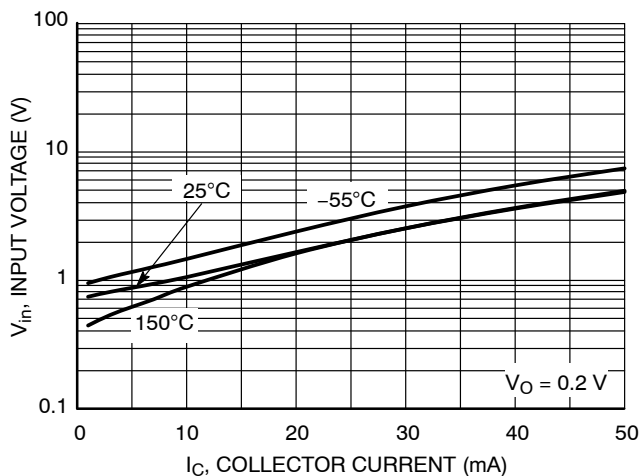
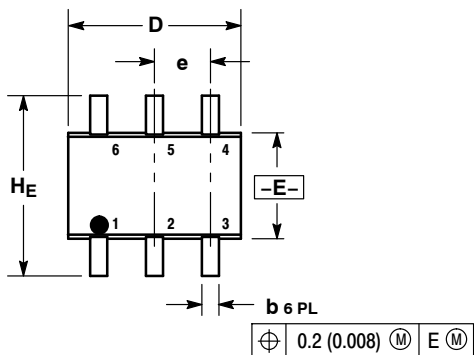


Figure 11. Input Voltage vs. Output Current

MUN5233DW1, NSBC143ZDXV6, NSBC143ZDP6

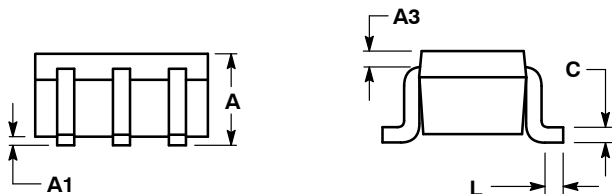
PACKAGE DIMENSIONS

SC-88/SC70-6/SOT-363
CASE 419B-02
ISSUE W

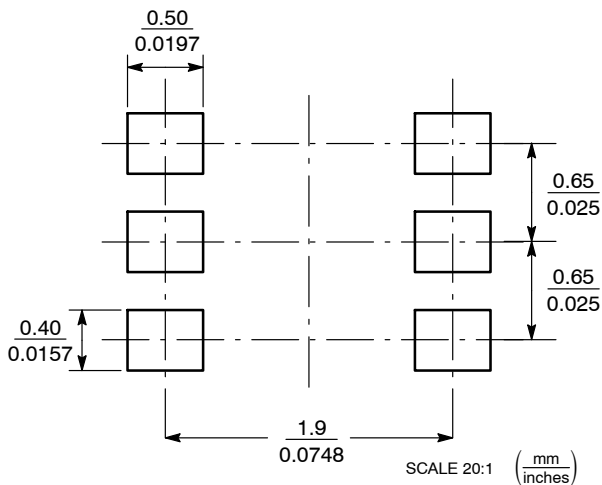


- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. 419B-01 OBSOLETE, NEW STANDARD 419B-02.

| DIM | MILLIMETERS | | | INCHES | | |
|-----|-------------|------|------|-----------|-------|-------|
| | MIN | NOM | MAX | MIN | NOM | MAX |
| A | 0.80 | 0.95 | 1.10 | 0.031 | 0.037 | 0.043 |
| A1 | 0.00 | 0.05 | 0.10 | 0.000 | 0.002 | 0.004 |
| A3 | 0.20 REF | | | 0.008 REF | | |
| b | 0.10 | 0.21 | 0.30 | 0.004 | 0.008 | 0.012 |
| C | 0.10 | 0.14 | 0.25 | 0.004 | 0.005 | 0.010 |
| D | 1.80 | 2.00 | 2.20 | 0.070 | 0.078 | 0.086 |
| E | 1.15 | 1.25 | 1.35 | 0.045 | 0.049 | 0.053 |
| e | 0.65 BSC | | | 0.026 BSC | | |
| L | 0.10 | 0.20 | 0.30 | 0.004 | 0.008 | 0.012 |
| He | 2.00 | 2.10 | 2.20 | 0.078 | 0.082 | 0.086 |



SOLDERING FOOTPRINT*



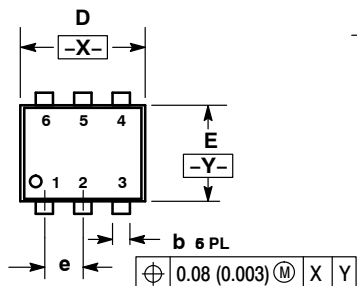
SC-88/SC70-6/SOT-363

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MUN5233DW1, NSBC143ZDXV6, NSBC143ZDP6

PACKAGE DIMENSIONS

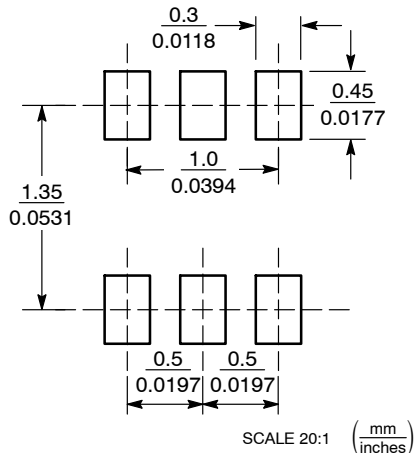
SOT-563, 6 LEAD
CASE 463A
ISSUE F



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETERS
 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

| DIM | MILLIMETERS | | | INCHES | | |
|----------------|-------------|------|------|----------|-------|-------|
| | MIN | NOM | MAX | MIN | NOM | MAX |
| A | 0.50 | 0.55 | 0.60 | 0.020 | 0.021 | 0.023 |
| b | 0.17 | 0.22 | 0.27 | 0.007 | 0.009 | 0.011 |
| C | 0.08 | 0.12 | 0.18 | 0.003 | 0.005 | 0.007 |
| D | 1.50 | 1.60 | 1.70 | 0.059 | 0.062 | 0.066 |
| E | 1.10 | 1.20 | 1.30 | 0.043 | 0.047 | 0.051 |
| e | 0.5 BSC | | | 0.02 BSC | | |
| L | 0.10 | 0.20 | 0.30 | 0.004 | 0.008 | 0.012 |
| H _E | 1.50 | 1.60 | 1.70 | 0.059 | 0.062 | 0.066 |

SOLDERING FOOTPRINT*

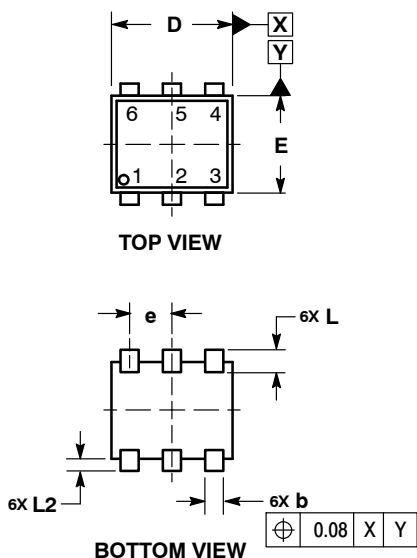


*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MUN5233DW1, NSBC143ZDXV6, NSBC143ZDP6

PACKAGE DIMENSIONS

SOT-963 CASE 527AD ISSUE E

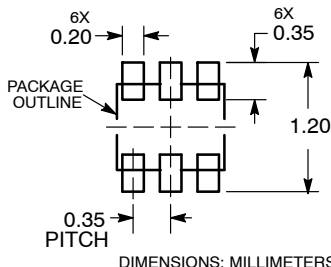


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

| DIM | MILLIMETERS | | |
|-------|-------------|------|------|
| | MIN | NOM | MAX |
| A | 0.34 | 0.37 | 0.40 |
| b | 0.10 | 0.15 | 0.20 |
| C | 0.07 | 0.12 | 0.17 |
| D | 0.95 | 1.00 | 1.05 |
| E | 0.75 | 0.80 | 0.85 |
| e | 0.35 BSC | | |
| H_E | 0.95 | 1.00 | 1.05 |
| L | 0.19 REF | | |
| L_2 | 0.05 | 0.10 | 0.15 |

RECOMMENDED MOUNTING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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JONHON

«JONHON» (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«FORSTAR» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели,
кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



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